

2DB1188P-13

2DB1188P-13 Information



mber	2DB1188P-13
cturer	Diodes Incorporated
у	Discrete Semiconductor Products Transistors - Bipolar (BJT) - Single
tion	TRANS PNP 32V 2A SOT89-3
e	TO-243AA
	For the pricing/inventory/lead time, please contact
	us
	Website: https://www.heisener.com
	E-mail: salesdept@heisener.com



Request a Quote

For Reference Only

Certified Quality

Heisener's commitment to quality has shaped our processes for sourcing, testing, shipping, and every step in between. This foundation underlies each component we sell.



2DB1188P-13 Specifications

Manufacturer Part Number	2DB1188P-13
Manufacturer	Diodes Incorporated
Category	Discrete Semiconductor Products
	Transistors - Bipolar (BJT) - Single
Package	TO-243AA
Series	-
Transistor Type	PNP
Current - Collector (Ic) (Max)	2A
Voltage - Collector Emitter Breakdown (Max)	32V
Vce Saturation (Max) @ Ib, Ic	800mV @ 200mA, 2A
Current - Collector Cutoff (Max)	100nA (ICBO)
DC Current Gain (hFE) (Min) @ Ic, Vce	82 @ 500mA, 3V
Power - Max	1W
Frequency - Transition	120MHz
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Package / Case	TO-243AA
Supplier Device Package	SOT-89-3
	Report errors?

2DB1188P-13 Guarantees



Quality Guarantees

We provide 90 days warranty. * If the items you received were not in perfect quality, we would be responsible for your refund or replacement, but the items must be returned in their original condition.

SERVICE EUARANTEE

Service Guarantees

We guarantee 100% customer satisfaction. Our experienced sales team and tech support team back our services to satisfy all our customers.

If you have any question about 2DB1188P-13, please do not hesitate to contact us! Website: https://www.heisener.com E-mail: salesdept@heisener.com